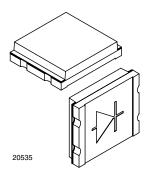


Vishay Semiconductors

Silicon PIN Photodiode, RoHS Compliant, Released for Lead (Pb)-free Reflow Soldering, AEC-Q101 Released



FEATURES

• Package type: surface mount

• Package form: top view



• Radiant sensitive area (in mm2): 4.4

AEC-Q101 qualified

High photo sensitivity

· High radiant sensitivity

· Suitable for visible and near infrared radiation

· Fast response times

• Angle of half sensitivity: $\varphi = \pm 65^{\circ}$

• Floor life: 72 h, MSL 4, acc. J-STD-020

· Lead (Pb)-free reflow soldering

· Lead (Pb)-free component

 Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

DESCRIPTION

TEMD5020X01 is a high speed and high sensitive PIN photodiode. It is a miniature surface mount device (SMD) including the chip with a 4.4 mm² sensitive area detecting visible and near infrared radiation.

APPLICATIONS

· High speed photo detectors

PRODUCT SUMMARY				
COMPONENT	I _{ra} (μΑ)	φ (deg)	λ _{0.1} (nm)	
TEMD5020X01	35	± 65	430 to 1100	

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
TEMD5020X01	Tape and reel	MOQ: 1500 pcs, 1500 pcs/reel	Top view		

Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Reverse voltage		V _R	60	V		
Power dissipation	T _{amb} ≤ 25 °C	P _V	215	mW		
Junction temperature		Tj	100	°C		
Operating temperature range		T _{amb}	- 40 to + 100	°C		
Storage temperature range		T _{stg}	- 40 to + 110	°C		
Soldering temperature	Acc. reflow solder profile fig. 8	T _{sd}	260	°C		
Thermal resistance junction/ambient	Soldered on PCB with pad dimensions: 4 mm x 4 mm	R _{thJA}	350	K/W		

Note

T_{amb} = 25 °C, unless otherwise specified

TEMD5020X01



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BASIC CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 50 mA	V _F		1	1.3	V
Breakdown voltage	I _R = 100 μA, E = 0	V _(BR)	60			V
Reverse dark current	V _R = 10 V, E = 0	I _{ro}		2	30	nA
Diada assasitas	$V_R = 0 \text{ V, f} = 1 \text{ MHz, E} = 0$	C _D		48		pF
Diode capacitance	$V_R = 3 \text{ V, f} = 1 \text{ MHz, E} = 0$	C _D		17	40	pF
Open circuit voltage	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	Vo		350		mV
Temperature coefficient of V _o	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	TK _{Vo}		- 2.6		mV/K
Short circuit current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	I _k		32		μΑ
Temperature coefficient of I _k	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	TK _{Ik}		0.1		%/K
Reverse light current	$E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}, \ V_{R} = 5 \text{ V}$	I _{ra}	25	35		μΑ
Angle of half sensitivity		φ		± 65		deg
Wavelength of peak sensitivity		λ_{p}		900		nm
Range of spectral bandwidth		λ 0.1		430 to 1100		nm
Noise equivalent power	$V_R = 10 \text{ V}, \lambda = 950 \text{ nm}$	NEP		4 x 10 ⁻¹⁴		W/√Hz
Rise time	$V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega,$ $\lambda = 820 \text{ nm}$	t _r		100		ns
Fall time	V_R = 10 V, R_L = 1 k Ω , λ = 820 nm	t _f		100		ns

Note

 T_{amb} = 25 °C, unless otherwise specified

BASIC CHARACTERISTICS

T_{amb} = 25 °C, unless otherwise specified

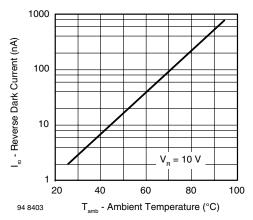


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

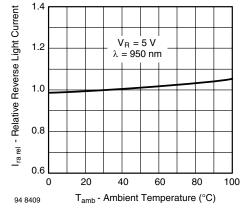


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature



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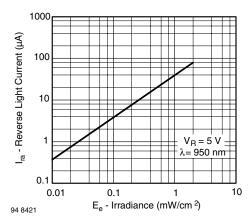


Fig. 3 - Reverse Light Current vs. Irradiance

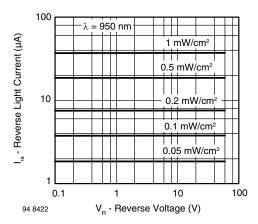


Fig. 4 - Reverse Light Current vs. Reverse Voltage

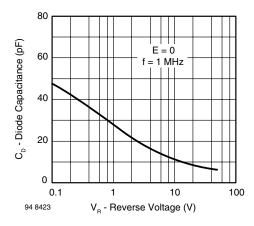


Fig. 5 - Diode Capacitance vs. Reverse Voltage

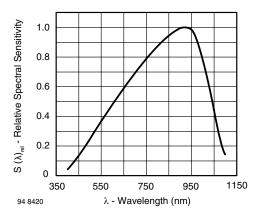


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

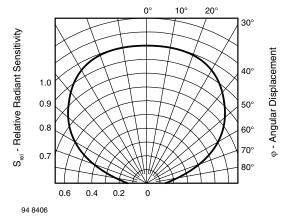
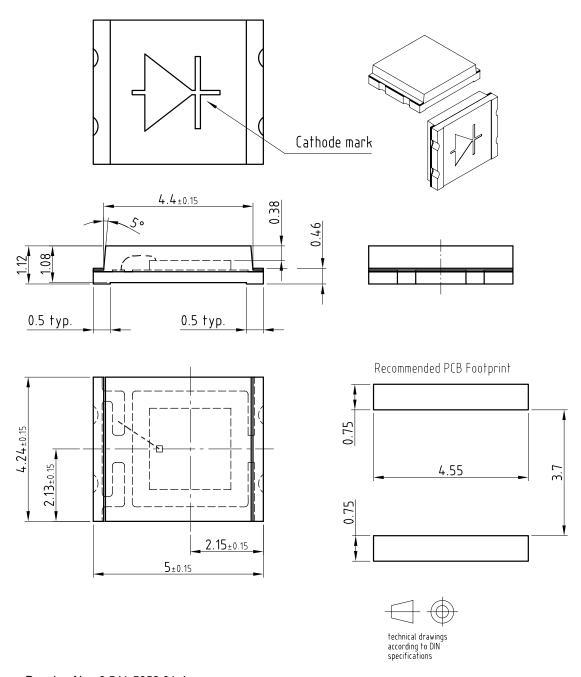


Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement

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PACKAGE DIMENSIONS in millimeters



Drawing-No.: 6.541-5059.01-4

Issue: 4; 26.04.07

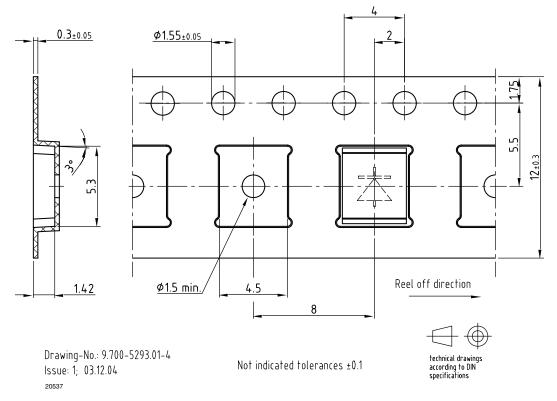
19280

Not indicated tolerances ± 0.1

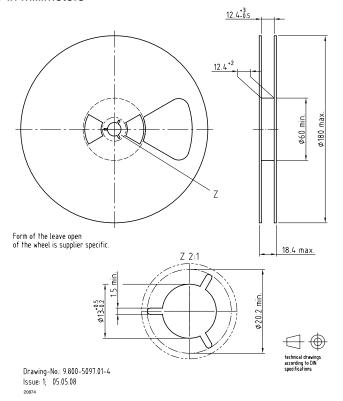


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TAPING DIMENSIONS in millimeters



REEL DIMENSIONS in millimeters



TEMD5020X01

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SOLDER PROFILE

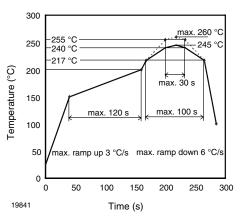


Fig. 8 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020D

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Time between soldering and removing from MBB must not exceed the time indicated in J-STD-020:

Moisture sensitivity: level 4

Floor life: 72 h

Conditions: T_{amb} < 30 °C, RH < 60 %

DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or recommended conditions:

192 h at 40 °C (+ 5 °C), RH < 5 %

or

96 h at 60 °C (+ 5 °C), RH < 5 %.



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